L Number	Hits		DB	Time stamp
1	397404	integrated adj2 circuit	USPAT;	2004/04/18 17:48
			US-PGPUB;	
			EPO; JPO;	
			DERWENT	
2	98333	semiconduct\$ adj2 layer\$	USPAT;	2004/04/18 17:49
			US-PGPUB;	
			EPO; JPO;	
			DERWENT	
3	147231	microorganism\$	USPAT;	2004/04/18 17:49
			US-PGPUB;	
			EPO; JPO;	
			DERWENT	
4	252	nutrient adj2 reservoir\$	USPAT;	2004/04/18 17:49
			US-PGPUB;	
			EPO; JPO;	
			DERWENT	
5	219089	metal adj2 oxide\$	USPAT;	2004/04/18 17:50
			US-PGPUB;	
			EPO; JPO;	
			DERWENT	0004/04/10 17 50
6	14421	(integrated adj2 circuit) and	USPAT;	2004/04/18 17:50
		(semiconduct\$ adj2 layer\$)	US-PGPUB;	
			EPO; JPO;	
	1		DERWENT	2004/04/18 17:51
8	T	(((integrated adj2 circuit) and	USPAT;	2004/04/18 17:51
		(semiconduct\$ adj2 layer\$)) and	US-PGPUB;	
		microorganism\$) and (nutrient adj2 reservoir\$)	EPO; JPO; DERWENT	į
9	1	((((integrated adj2 circuit) and	USPAT;	2004/04/18 17:52
9	1	((((integrated adj2 circuit) and (semiconduct\$ adj2 layer\$)) and	US-PGPUB;	2004/04/18 17.32
		microorganism\$) and (nutrient adj2	EPO; JPO;	
		reservoir\$)) and (metal adj2 oxide\$)	DERWENT	
7	31	1	USPAT;	2004/04/18 17:52
'	31	(semiconduct\$ adj2 layer\$)) and	US-PGPUB;	2001/01/10 1/.02
		microorganism\$	EPO; JPO;	
		and the state of t	DERWENT	
L			Duringin	